

# The RF Line

## NPN Silicon

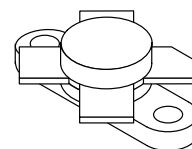
### RF Power Transistor

... designed for high gain driver and output linear amplifier stages in 1.5 to 30 MHz HF/SSB equipment.

- Specified 28 Volt, 30 MHz Characteristics —  
Output Power = 25 W (PEP)  
Minimum Gain = 22 dB  
Efficiency = 35%
- Intermodulation Distortion @ 25 W (PEP) —  
IMD = -30 dB (Max)
- 100% Tested for Load Mismatch at all Phase Angles with 30:1 VSWR
- Class A and AB Characterization
- BLX 13 Equivalent

**MRF426**

**25 W (PEP), 30 MHz  
RF POWER  
TRANSISTOR  
NPN SILICON**



CASE 211-07, STYLE 1

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	35	Vdc
Collector-Base Voltage	$V_{CBO}$	65	Vdc
Emitter-Base Voltage	$V_{EBO}$	4.0	Vdc
Collector Current — Continuous	$I_C$	3.0	Adc
Withstand Current — 5 s	—	6.0	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ (1) Derate above $25^\circ\text{C}$	$P_D$	70 0.4	Watts W/ $^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +150	$^\circ\text{C}$

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	$^\circ\text{C}/\text{W}$

#### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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#### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ( $I_C = 50 \text{ mAdc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	35	—	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 50 \text{ mAdc}$ , $I_E = 0$ )	$V_{(BR)CBO}$	65	—	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \text{ mAdc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector Cutoff Current ( $V_{CE} = 28 \text{ Vdc}$ , $V_{BE} = 0$ )	$I_{CES}$	—	—	10	mAdc

NOTE:

- This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

(continued)

**ELECTRICAL CHARACTERISTICS — continued** ( $T_C = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b>					
DC Current Gain ( $I_C = 1.0 \text{ Adc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$	10	35	—	—

**DYNAMIC CHARACTERISTICS**

Output Capacitance ( $V_{CB} = 30 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{ob}$	—	60	80	pF
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**FUNCTIONAL TESTS (SSB)**

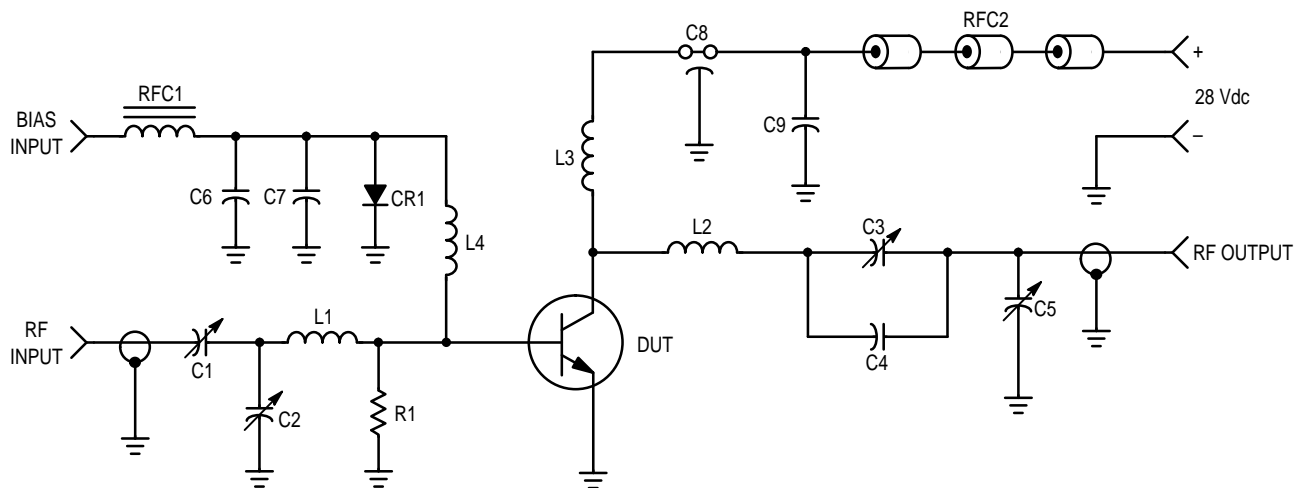
Common-Emitter Amplifier Gain ( $V_{CC} = 28 \text{ Vdc}$ , $P_{out} = 25 \text{ W (PEP)}$ , $f_1 = 30 \text{ MHz}$ , $f_2 = 30.001 \text{ MHz}$ , $I_{CQ} = 25 \text{ mA}$ )	$G_{PE}$	22	25	—	dB
Collector Efficiency ( $V_{CC} = 28 \text{ Vdc}$ , $P_{out} = 25 \text{ W (PEP)}$ , $f_1 = 30 \text{ MHz}$ , $f_2 = 30.001 \text{ MHz}$ , $I_{CQ} = 25 \text{ mA}$ )	$\eta$	35	—	—	%
Intermodulation Distortion (2) ( $V_{CC} = 28 \text{ Vdc}$ , $P_{out} = 25 \text{ W (PEP)}$ , $f_1 = 30 \text{ MHz}$ , $f_2 = 30.001 \text{ MHz}$ , $I_{CQ} = 25 \text{ mA}$ )	$IMD(d3)$	—	-35	-30	dB
Load Mismatch ( $V_{CC} = 28 \text{ Vdc}$ , $P_{out} = 25 \text{ W (PEP)}$ , $f_1 = 30 \text{ MHz}$ , $f_2 = 30.001 \text{ MHz}$ , $I_{CQ} = 25 \text{ mA}$ , $VSWR 30:1$ at All Phase Angles)	$\psi$	No Degradation in Output Power			

**CLASS A PERFORMANCE**

Intermodulation Distortion (2) and Power Gain ( $V_{CC} = 28 \text{ Vdc}$ , $P_{out} = 8.0 \text{ W (PEP)}$ , $f_1 = 30 \text{ MHz}$ , $f_2 = 30.001 \text{ MHz}$ , $I_{CQ} = 1.2 \text{ Adc}$ )	$G_{PE}$ $IMD(d3)$ $IMD(d5)$	— — —	23.5 -40 -55	— — —	dB
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NOTE:

2. To Mil-Std-1311 Version A, Test Method 2204B, Two Tone, Reference each Tone.



C1, C2 — ARCO 469, 190–780 pF  
 C3, C4 — ARCO 464, 25–280 pF  
 C5 — 120 pF Dipped Mica  
 C6, C7 — 100  $\mu\text{F}$ , 15 Vdc  
 C8 — 680 pF F.T. Allen Bradley  
 C9 — 1.0  $\mu\text{F}$  35 V Tantalum  
 CR1 — 1N4997

L1 — 3 Turns #16 0.25" ID  
 L2 — 6 Turns #16 0.5" ID  
 L3 — 7 Turns #20 0.38" ID  
 L4 — 10  $\mu\text{H}$  Molded Choke Delevan  
 RFC1 — Ferroxcube VK200/20-4B  
 RFC2 — 3-Ferroxcube 5653065-3B  
 RF — Input/Output Connectors UG53 A/ $\mu$   
 R1 — 10  $\Omega$  1/2 Watt 10%

Adjust Bias (Base) for  $I_{CQ} = 20 \text{ mA}$  with No RF Applied

**Figure 1. 30 MHz Linear Test Circuit**

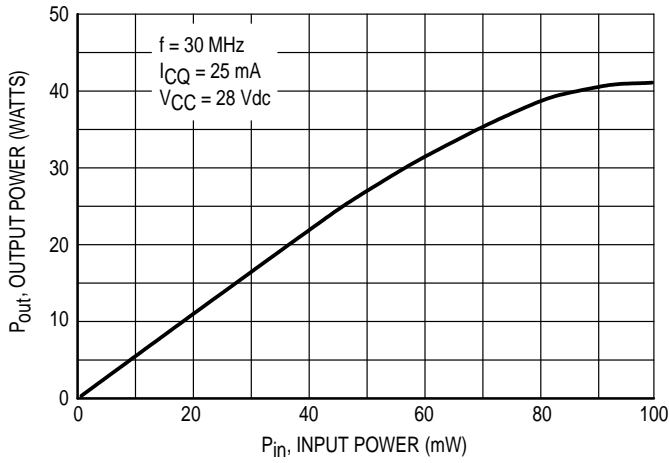


Figure 2. Output Power versus Input Power

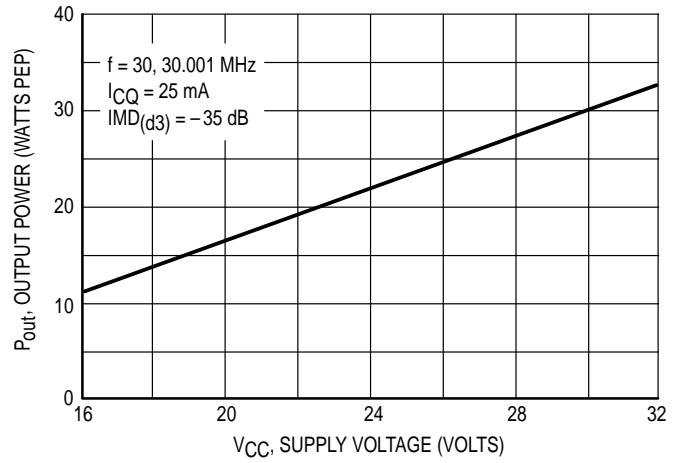


Figure 3. Output Power versus Supply Voltage

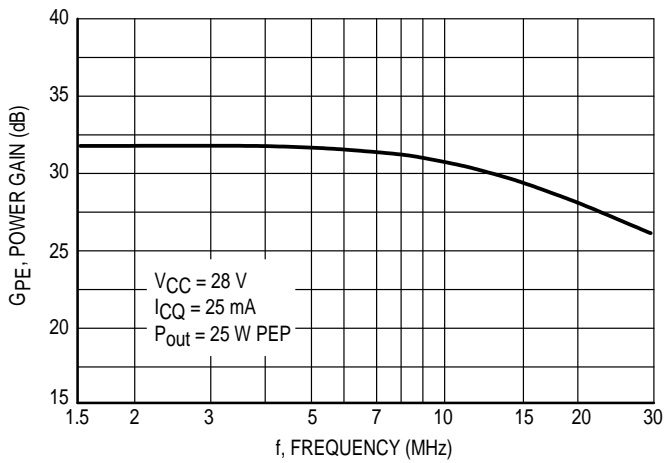


Figure 4. Power Gain versus Frequency

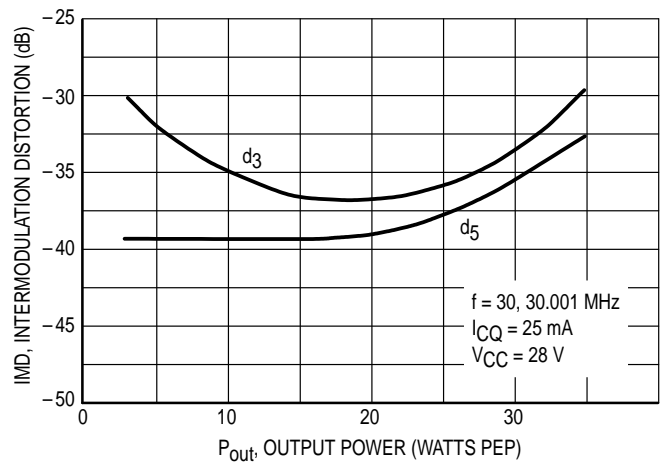


Figure 5. Intermodulation Distortion versus Output Power

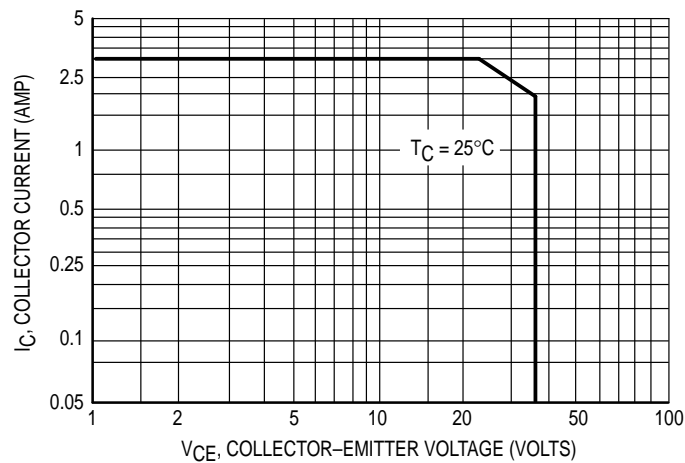


Figure 6. DC Safe Operating Area

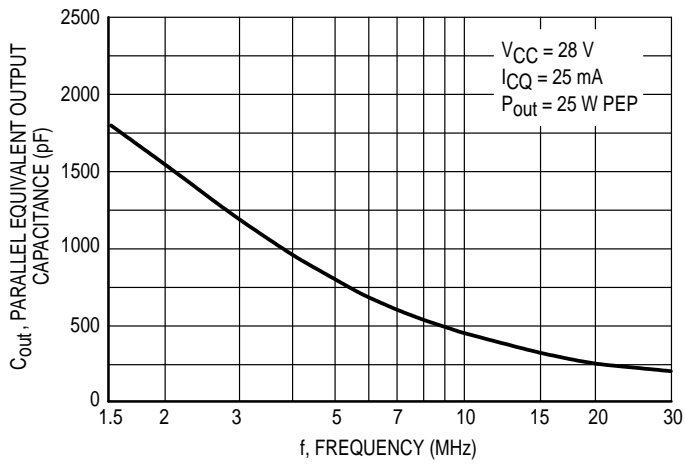


Figure 7. Output Capacitance versus Frequency

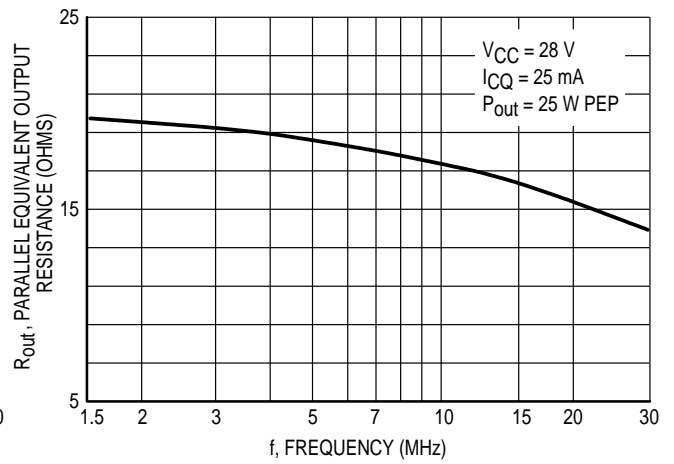


Figure 8. Output Resistance versus Frequency

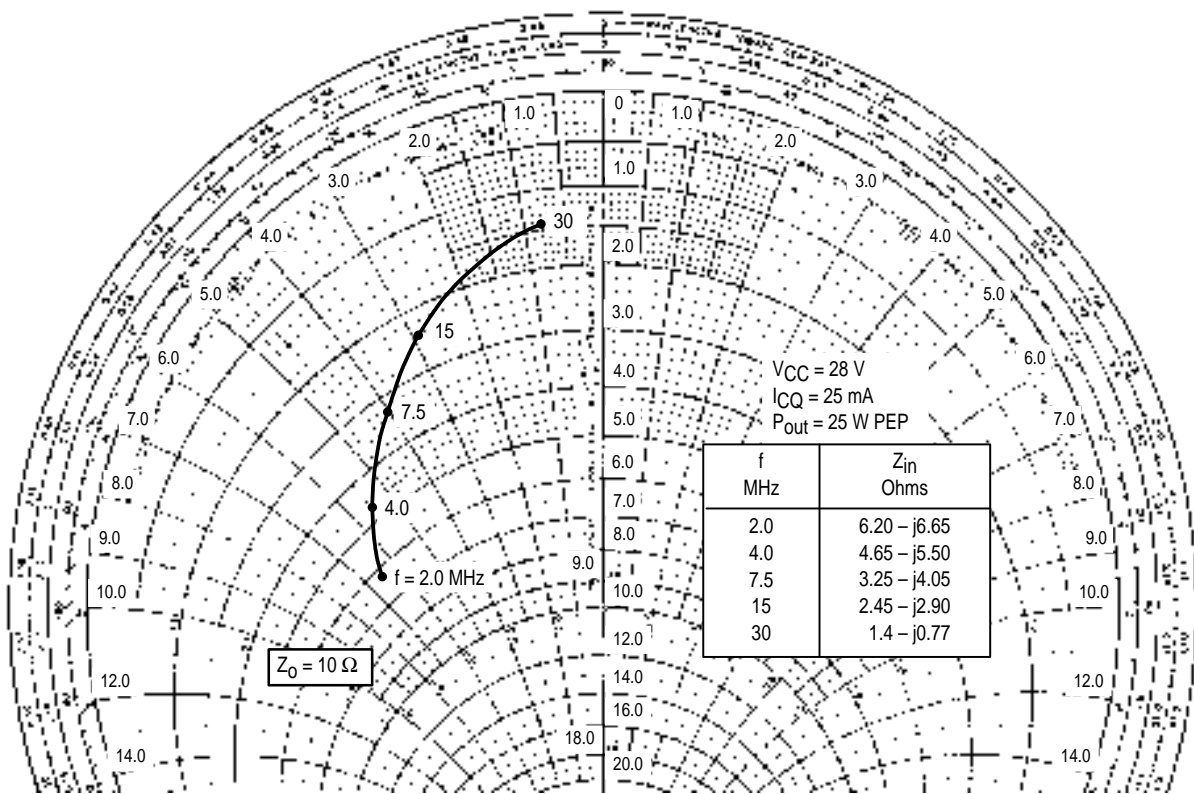
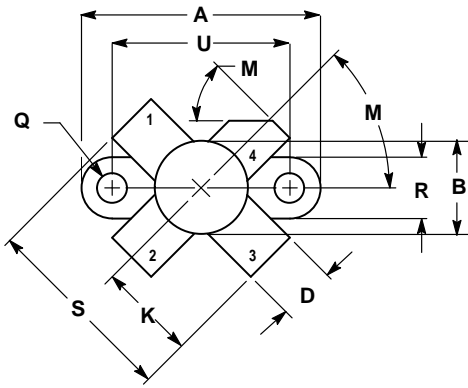


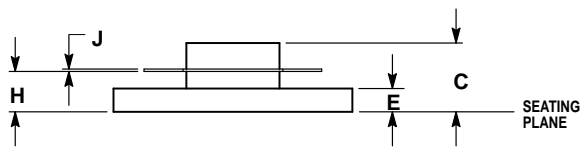
Figure 9. Series Equivalent Input Impedance

# PACKAGE DIMENSIONS




- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.960	0.990	24.39	25.14
B	0.370	0.390	9.40	9.90
C	0.229	0.281	5.82	7.13
D	0.215	0.235	5.47	5.96
E	0.085	0.105	2.16	2.66
H	0.150	0.108	3.81	4.57
J	0.004	0.006	0.11	0.15
K	0.395	0.405	10.04	10.28
M	40°	50°	40°	50°
Q	0.113	0.130	2.88	3.30
R	0.245	0.255	6.23	6.47
S	0.790	0.810	20.07	20.57
U	0.720	0.730	18.29	18.54



- STYLE 1:  
 PIN 1. EMITTER  
 2. BASE  
 3. EMITTER  
 4. COLLECTOR

**CASE 211-07  
 ISSUE N**

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